

74LCX16240

Low voltage CMOS 16-bit bus buffer (3-state) with 5V tolerant inputs and outputs

Features

- 5V tolerant inputs and outputs
- High speed:
 - t_{PD} = 4.5ns (Max) at V_{CC} = 3V
- Power down protection on inputs and outputs
- Symmetrical output impedance:
 II_{OH}I = I_{OL} = 24mA (Min) at V_{CC} = 3V
- PCI bus levels guaranteed at 24mA
- Balanced propagation delays:
 - $t_{PLH} \cong t_{PHL}$
- Operating voltage range:
 - V_{CC} (Opr) = 2.0V to 3.6V
- Pin and function compatible with 74 series 16240
- Latch-up performance exceeds 500mA (JESD 17)
- ESD performance:
 - HBM > 2000V (MIL STD 883 method 3015); MM > 200V



Description

The 74LCX16240 is a low voltage CMOS 16 BIT BUS BUFFER fabricated with sub-micron silicon gate and double-layer metal wiring C^2MOS technology. It is ideal for low power and high speed 3.3V applications; it can be interfaced to 5V signal environment for both inputs and outputs.

Any nG output control governs four BUS BUFFERS. Output Enable input $(n\overline{G})$ tied together gives full 16-bit operation.

When $n\overline{G}$ is LOW, the outputs are on. When nG is HIGH, the output are in high impedance state.

This device is designed to be used with 3 state memory address drivers, etc.

It has same speed performance at 3.3V than 5V AC/ACT family, combined with a lower power consumption.

All inputs and outputs are equipped with protection circuits against static discharge, giving them 2KV ESD immunity and transient excess voltage.

Order codes

Part number	Package	Packaging
74LCX16240TTR	TSSOP48	Tape and reel

February 2007

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1 Logic symbols and I/O equivalent circuit

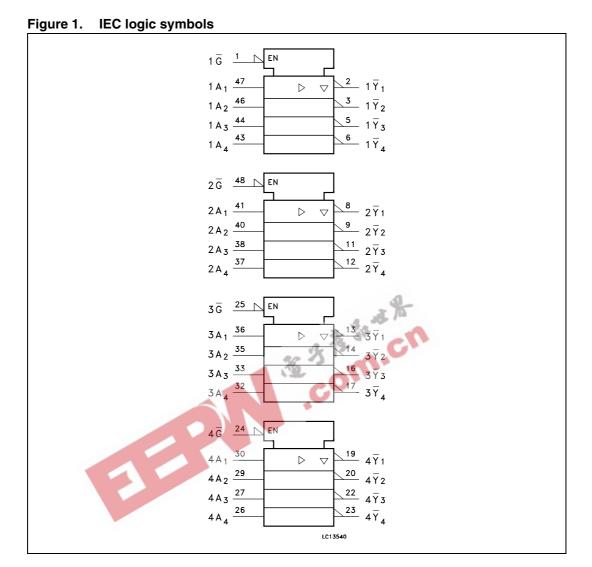
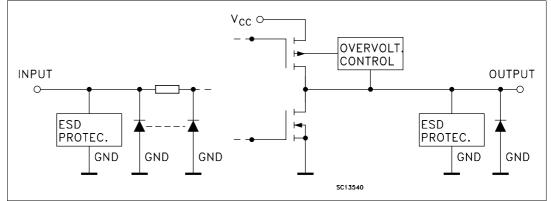


Figure 2. Input and output equivalent circuit

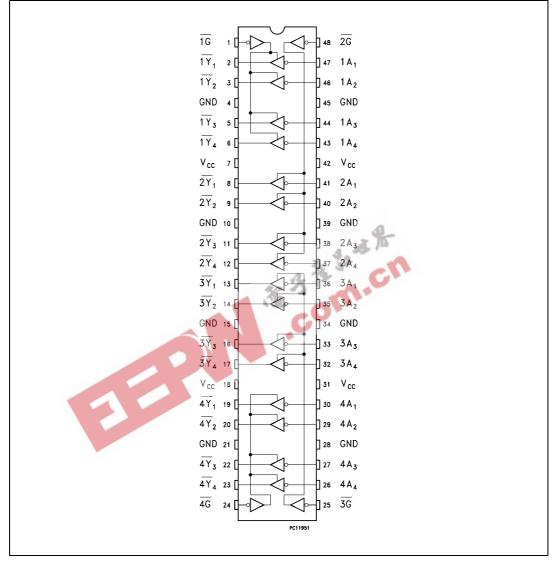




2 Pin settings

2.1 Pin connection

Figure 3. Pin connection (top through view)





Pin description 2.2

Table 1. Pin description

Pin N°	Symbol	Name and function
1	1 G	Output enable input
2, 3, 5, 6	1Y1 to 1Y4	Data outputs
8, 9, 11, 12	$\overline{2Y1}$ to $\overline{2Y4}$	Data outputs
13, 14, 16, 17	$\overline{3Y1}$ to $\overline{3Y4}$	Data outputs
19, 20, 22, 23	$\overline{4Y1}$ to $\overline{4Y4}$	Data outputs
24	4 G	Output enable input
25	3 G	Output enable input
30, 29, 27, 26	4A1 to 4A4	Data outputs
36, 35, 33, 32	3A1 to 3A4	Data outputs
41, 40, 38, 37	2A1 to 2A4	Data outputs
47, 46, 44, 43	1A1 to 1A4	Data outputs
48	2 G	Output enable input
4, 10, 15, 21, 28, 34, 39, 45	GND	Ground (0V)
7, 18, 31, 42	V _{cc}	Positive supply voltage
Logic states Truth table		COL

3

3.1

Table 2. Truth table

Inp	Output	
G	An	Yn
L	L	Н
L	Н	L
Н	Х	Z

Note:

Z : High impedance

X : Do not care



4 Maximum rating

Stressing the device above the rating listed in the "absolute maximum ratings" table may cause permanent damage to the device. these are stress ratings only and operation of the device at these or any other conditions above those indicated in the operating sections of this specification is not implied. exposure to absolute maximum rating conditions for extended periods may affect device reliability. refer also to the STMicroelectronics sure program and other relevant quality documents.

Symbol	Parameter	Value	Unit
V _{CC}	Supply voltage	-0.5 to +7.0	V
VI	DC input voltage	-0.5 to +7.0	V
Vo	DC output voltage (OFF state)	-0.5 to +7.0	V
Vo	DC output voltage (high or low state) ⁽¹⁾	-0.5 to V _{CC} + 0.5	V
Ι _{ΙΚ}	DC input diode current	-50	mA
I _{OK}	DC output diode current ⁽²⁾	-50	mA
Ι _Ο	DC output current	±50	mA
I _{CC}	DC supply current per supply pin	± 100	mA
I _{GND}	DC ground current per supply pin	± 100	mA
T _{stg}	Storage temperature	-65 to +150	°C
Τ _L	Lead temperature (10 sec)	300	°C

Table 3.	Absolute	maximum	ratings
10010 01	710001010	maximani	racingo

- 1. I_O absolute maximum rating must be observed
- 2. V_O < GND

4.1 Recommended operating conditions

Table 4. Recommended operating conditions

Symsbol	Parameter	Value	Unit
V _{CC}	Supply voltage ⁽¹⁾	2.0 to 3.6	V
VI	Input voltage	0 to 5.5	V
Vo	Output voltage (OFF state)	0 to 5.5	V
Vo	Output voltage (high or low state)	0 to V _{CC}	V
I _{OH} , I _{OL}	High or low level output current ($V_{CC} = 3.0$ to 3.6V)	± 24	mA
I _{OH} , I _{OL}	High or low level output current ($V_{CC} = 2.7V$)	± 12	mA
T _{op}	Operating temperature	-40 to 85	°C
dt/dv	Input rise and fall time ⁽²⁾	0 to 10	ns/V

1. Truth table guaranteed: 1.5V to 3.6V

2. V_{IN} from 0.8V to 2V at V_{CC} = 3.0V



5 Electrical characteristics

	Specifications	-		1/-1		
		10	est condition	Val		_
Symbol	Parameter	V _{cc}		-40 to 85°C		Unit
		(V)		Min	Мах	
V _{IH}	High level input voltage	2.7 to 3.6		2.0		V
V _{IL}	Low level input voltage	2.7 10 3.0			0.8	V
		2.7 to 3.6	I _O = -100μA	V _{CC} -0.2		
V _{OH}		2.7	I _O = -12mA	2.2		v
⊻он	High level output voltage	3.0	I _O = -18mA	2.4		V
		3.0	I _O = -24mA	2.2		
		2.7 to 3.6	I _O = 100μA		0.2	
Ve		2.7	I _O = 12mA		0.4	v
V _{OL}	Low level output voltage	2.0	I _O = 16mA		0.4	
		3.0	1 ₀ = 24mA		0.55	
I _I	Input leakage current	2.7 to 3.6	$V_1 = 0$ to 5.5V		± 5	μA
I _{off}	Power OFF leakage current	0	$V_1 \text{ or } V_0 = 5.5 V$		10	μA
I _{OZ}	High impedance output leakage current	2.7 to 3.6	$V_{I} = V_{IH} \text{ or } V_{IL}$ $V_{O} = 0 \text{ to } V_{CC}$		± 5	μA
		0.74-0.0	$V_{I} = V_{CC}$ or GND		20	
Icc	Quiescent supply current	2.7 to 3.6	$V_{\rm I}$ or $V_{\rm O}$ = 3.6 to 5.5V		± 20	- μΑ
ΔI_{CC}	l incr. per Input	2.7 to 3.6	$V_{IH} = V_{CC} - 0.6V$		500	μA

Table 5. DC specifications

Table 6. Dynamic switching characteristics

		Те	st condition		Value		
Symbol	Parameter	v _{cc}		T,	_A = 25 °	°C	Unit
		(V)		Min	Тур	Max	
V _{OLP}	Dynamic low level quiet	3.3	C _L = 50pF V _{IL} = 0V, V _{IH} = 3.3V		0.8		v
V _{OLV}	output ⁽¹⁾	3.3	$V_{IL} = 0V, V_{IH} = 3.3V$		-0.8		v

1. Number of outputs defined as "n". Measured with "n-1" outputs switching from HIGH to LOW or LOW to HIGH. The remaining output is measured in the LOW state.



			Test condition				Value		
Symbol	Parameter	V _{cc}	CL	RL	t _s = t _r	-40 to	85 °C	Unit	
		(V)	(pF)	(Ω)	(ns)	Min	Max		
t _{PLH} t _{PHL}	Propagation delay	2.7	50	500	2.5	1.5	5.3	ns	
	time	3.0 to 3.6				1.5	4.5		
t _{PZL} t _{PZH}	Output enable	2.7	50	500	2.5	1.5	6.0	ns	
	time	3.0 to 3.6				1.5	5.4		
t _{PLZ} t _{PHZ}	Output disable	2.7	50	500	2.5	1.5	5.4	ns	
	time	3.0 to 3.6				1.5	5.3		
t _{OSLH} t _{OSHL}	Output to output skew time ⁽¹⁾ ⁽²⁾	3.0 to 3.6	50	500	2.5		1.0	ns	

Table 7. AC electrical characteristics

 Skew is defined as the absolute value of the difference between the actual propagation delay for any two outputs of the same device switching in the same direction, either HIGH or LOW (t_{OSLH} = | t_{PLHm} - t_{PLHn}|, t_{OSHL} = | t_{PHLm} - t_{PHLn}|)

2. Parameter guaranteed by design

Table 8. Capacitive characteristics

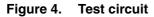
		Tes	st condition		Value		
Symbol	Parameter	V _{cc}	3 3	Т	_A = 25 °	С	Unit
		(V)		Min	Тур	Max	
C _{IN}	Input capacitance	3.3	$V_{IN} = 0$ to V_{CC}		7		pF
C _{OUT}	Output capacitance	3.3	$V_{\rm IN} = 0$ to $V_{\rm CC}$		15		pF
C _{PD}	Power dissipation capacitance ⁽¹⁾	3.3	$f_{IN} = 10MHz$ $V_{IN} = 0 \text{ or } V_{CC}$		60		pF

£___

1. C_{PD} is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load. (Refer to Test Circuit). Average operating current can be obtained by the following equation. $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/16$ (per circuit)



6 Test circuit



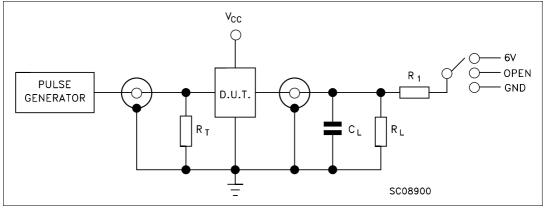


Figure 5. Test circuit

Test	Switch
t _{PLH} , t _{PHL}	Open
t _{PZL} , t _{PLZ}	6V
t _{PZH} , t _{PHZ}	GND

.

 $C_L = 50 pF$ or equivalent (includes jig and probe capacitance)

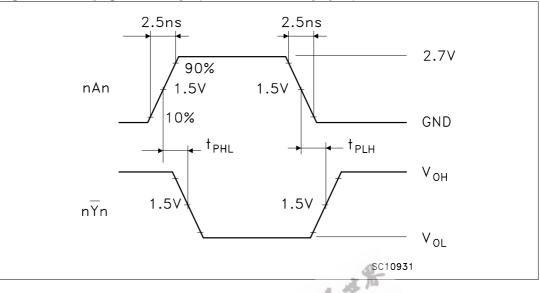
 $R_L = R_1 = 500\Omega$ or equivalent

 $R_T = Z_{OUT}$ of pulse generator (typically 50 Ω)

3-

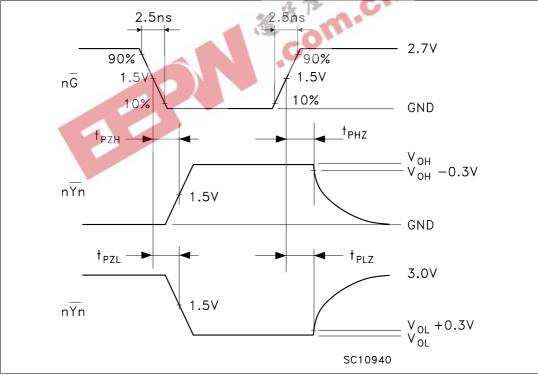


7 Waveforms











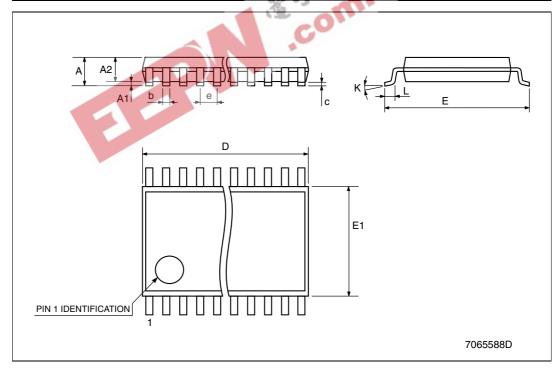
8 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com



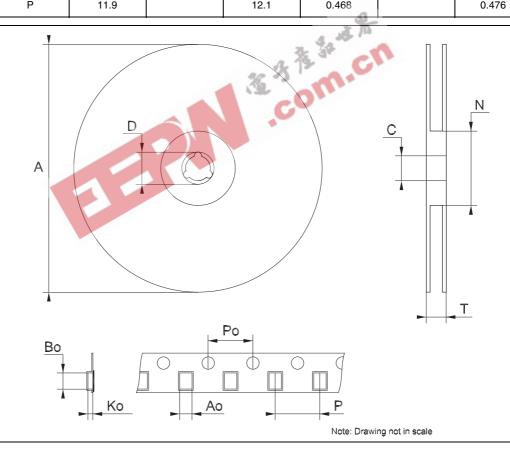


	TSSOP48 MECHANICAL DATA								
DIM.	mm.			inch					
	MIN.	ТҮР	MAX.	MIN.	TYP.	MAX.			
А			1.2			0.047			
A1	0.05		0.15	0.002		0.006			
A2		0.9			0.035				
b	0.17		0.27	0.0067		0.011			
с	0.09		0.20	0.0035		0.0079			
D	12.4		12.6	0.488		0.496			
E		8.1 BSC			0.318 BSC				
E1	6.0		6.2	0.236		0.244			
е		0.5 BSC		ß	0.0197 BSC				
к	0°		8°	00		8°			
L	0.45		0.75	0.018		0.030			





DIM.	mm.			inch		
	MIN.	ТҮР	MAX.	MIN.	TYP.	MAX.
А			330			12.992
С	12.8		13.2	0.504		0.519
D	20.2			0.795		
Ν	60			2.362		
Т			30.4			1.197
Ao	8.7		8.9	0.343		0.350
Во	13.1		13.3	0.516		0.524
Ko	1.5		1.7	0.059		0.067
Po	3.9		4.1	0.153		0.161
Р	11.9		12.1	0.468		0.476



9 Revision history

Table 9. Revision history

Date	Revision	Changes	
15-Sep-2004	4	Ordering Codes Revision - pag. 1.	
02-Feb-2007	5	Document reformatted, temperature ranges updated	



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